TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOSVI-H)

# **TPC8048-H**

# Switching Regulator Applications Motor Drive Applications DC-DC Converter Applications

- · Small footprint due to a small and thin package
- High-speed switching
- Small gate charge: Q<sub>SW</sub> = 17 nC (typ.)
- Low drain-source ON-resistance:

 $R_{DS(ON)} = 4.6 \text{ m}\Omega \text{ (typ.)}$ 

- High forward transfer admittance: |Y<sub>fs</sub>| = 60 S (typ.)
- Low leakage current:  $I_{DSS} = 10 \mu A \text{ (max) (V}_{DS} = 60 \text{ V)}$
- Enhancement mode:  $V_{th} = 1.3$  to 2.3 V ( $V_{DS} = 10$  V,  $I_D = 1.0$  mA)

#### **Absolute Maximum Ratings (Ta = 25°C)**

Characte	eristic	Symbol	Rating	Unit	
Drain-source voltage		$V_{DSS}$	60	V	
Drain-gate voltage (R	$R_{GS} = 20 \text{ k}\Omega$	$V_{DGR}$	60	V	
Gate-source voltage		$V_{GSS}$	±20	V	
Drain current	DC (Note 1)	ΙD	16	Α	
Drain current	Pulsed (Note 1)	$I_{DP}$	64	A	
Drain power dissipation	on (t = 10 s) (Note 2a)	$P_{D}$	1.9	W	
Drain power dissipation	on (t = 10 s) (Note 2b)	P <sub>D</sub>	1.0	W	
Single-pulse avalanch	he energy (Note 3)	E <sub>AS</sub>	92	mJ	
Avalanche current		I <sub>AR</sub>	16	Α	
Repetitive avalanche	energy c = 25°C) (Note 4)	E <sub>AR</sub>	0.05	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature	range	T <sub>stg</sub>	-55 to 150	°C	

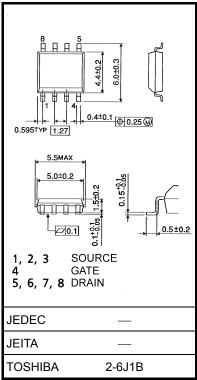
Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

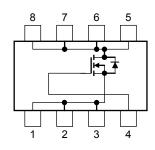
This transistor is an electrostatic-sensitive device. Handle with care.

Unit: mm



Weight: 0.085g (typ.)

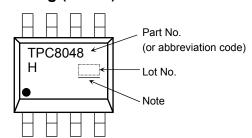
#### **Circuit Configuration**



#### **Thermal Characteristics**

Characteristic	Symbol	Max	Unit	
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R <sub>th (ch-a)</sub>	65.8	°C/W	
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R <sub>th (ch-a)</sub>	125	°C/W	

#### Marking (Note 5)



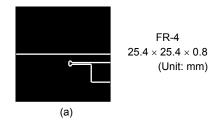
Note: A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

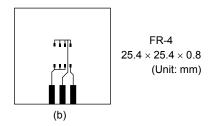
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)

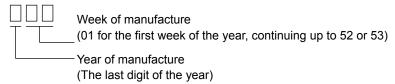




Note 3:  $V_{DD}=24~V,~T_{ch}=25^{\circ}C$  (initial),  $L=500~\mu H,~R_{G}=25~\Omega,~I_{AR}=16~A$ 

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: \* Weekly code: (Three digits)



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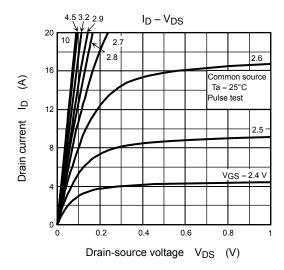
## **Electrical Characteristics (Ta = 25°C)**

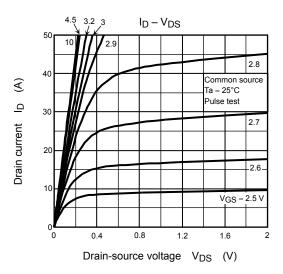
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	nt	I <sub>DSS</sub>	V <sub>DS</sub> = 60 V, V <sub>GS</sub> = 0 V	_	_	10	μА
Drain aguras bra	rain-source breakdown voltage		$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	60	_	_	V
Drain-source brea	akdown voltage	V <sub>(BR) DSX</sub>	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	45	_	_	V
Gate threshold vo	oltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1.0 mA	1.3	_	2.3	V
Drain-source ON-	rosistanco	Pro (OV)	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 8 A	_	5.1	7.4	mΩ
Drain-source ON	-resistance	R <sub>DS</sub> (ON)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 8 A	60 — — 45 — — 1.3 — 2.3	1115.2		
Forward transfer	admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 8 A	30	60	_	S
Input capacitance	)	C <sub>iss</sub>		_	5800	7540	pF
Reverse transfer	capacitance	C <sub>rss</sub>	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	210	315	
Output capacitance		Coss			650	_	
Gate resistance		rg	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	1.0 1.5		Ω
Switching time	Rise time	t <sub>r</sub>	V <sub>GS</sub> 10 V	_	3.7	_	ns
	Turn-on time	t <sub>on</sub>		_	14	_	
	Fall time	t <sub>f</sub>		_	7.6	_	
	Turn-off time	t <sub>off</sub>	$V_{DD} \approx 30 \text{ V}$ Duty $\leq$ 1%, $t_W = 10 \mu\text{s}$	_	68	_	
Total gate charge		_	$V_{DD} \approx 48 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 16 \text{ A}$		87	_	
(gate-source plus	gate-drain)	Qg	$V_{DD} \approx 48 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 16 \text{ A}$	<u> </u>		_	
Gate-source charge 1		Q <sub>gs1</sub>		_	14	_	nC
Gate-drain ("Miller") charge		Q <sub>gd</sub>	$V_{DD} \approx 48 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 16 \text{ A}$	_	12	_	
Gate switch charg	ge	Q <sub>SW</sub>		_	17	_	

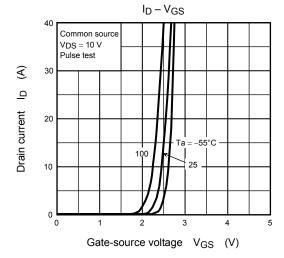
### **Source-Drain Ratings and Characteristics (Ta = 25°C)**

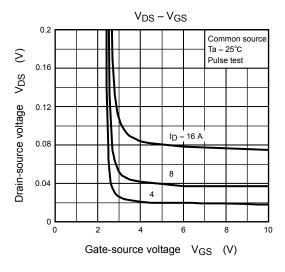
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Peak forward current	Pulse	(Note 1)	I <sub>FP</sub>	_	_	_	64	Α
Forward voltage (diode)			$V_{DSF}$	I <sub>DR</sub> = 16 A, V <sub>GS</sub> = 0 V		_	-1.2	V

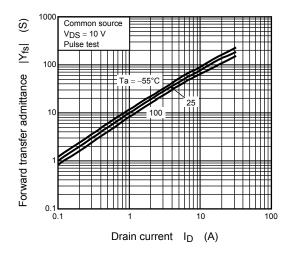
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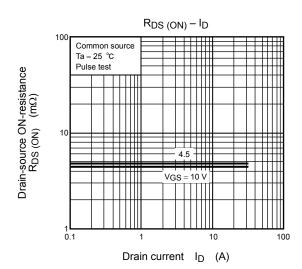


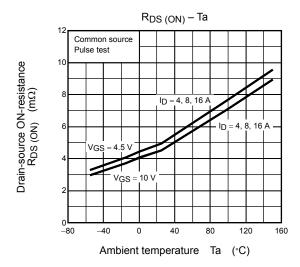


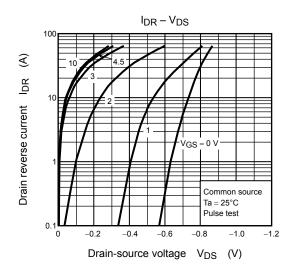


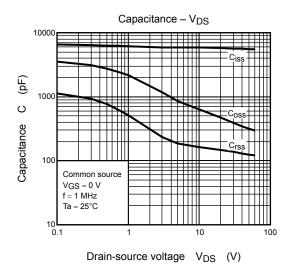


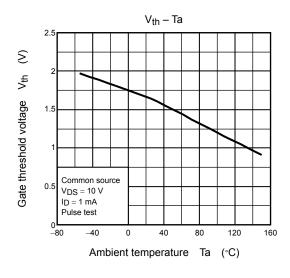


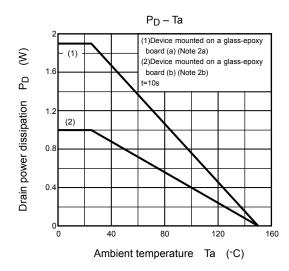


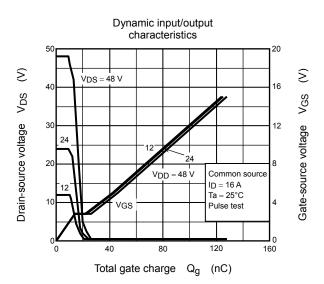


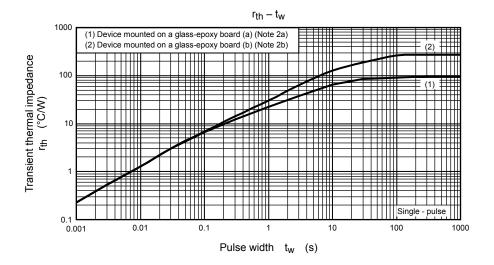


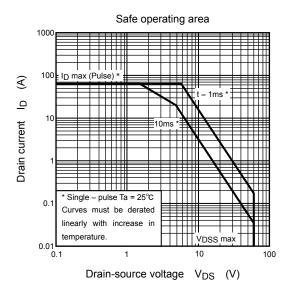












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